

N-Channel Logic Level Enhancement Mode Power MOSFET

Description

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low rDS(on) and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- VDS=30V, ID=50A, RDS(ON)=9mΩ
- Low Gate Charge
- · Repetitive Avalanche Rated
- · Simple Drive Requirement
- · Fast Switching Characteristic
- RoHS compliant package

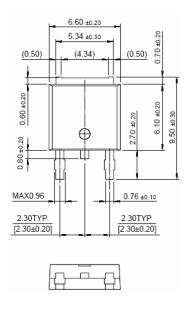
Packing & Order Information

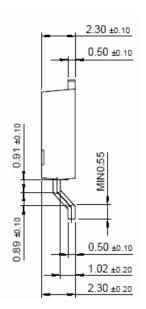
Part No./T: 2,500/Reel

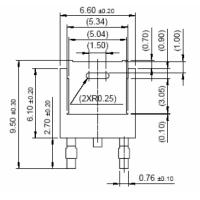
Part No./ R: 80/Tube, 4,000/Box



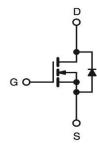
RoHS COMPLIANT







Graphic symbol



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)						
Symbol	Parameter	Value	Unit			
V_{DS}	Drain-Source Voltage	30	V			
V _{GS}	Gate-Source Voltage	±30	V			
I _D	Continuous Drain Current @ TC=25°C	50	Α			
	Continuous Drain Current @ TC=100°C	35	А			



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Absolute Maximum Ratings (Tc=25°C unless otherwise noted)					
Symbol	Parameter	Value	Unit		
I _{DM} *1	Pulsed Drain Current	140	Α		
I _{AS}	Avalanche Current	37.5	А		
E _{AS}	Avalanche Energy @ L=0.1mH , ID = 37.5 A , Rg = 25 Ω	70	mJ		
E _{AR} *2	Repetitive Avalanche Energy @ L=0.05mH	15	mJ		
P _D	Power Dissipation (TC=25°C)	60	W		
	Power Dissipation (TC=100°C)	32	W		
T _J /T _{STG}	Operating Junction and Storage Temperature	-55 to +150	°C		

Note:

100% UIS testing in condition of VD=15V, L=0.1mH, VG=10V, IL=25A, Rated VDS=25V N-CH

^{*2.} Duty cycle≤1%

Thermal Characteristics (Tc=25°C unless otherwise noted)					
Symbol	Parameter	Maximum	Units		
Rthjc	Typical thermal resistance	2.5	°C/W		
$R_{\theta JA}$	Typical thermal resistance	75	C/VV		

Static Characteristics					
Symbol	Test Conditions	Min	Тур.	Max.	Units
V_{GS}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0	1.7	3.0	V
*D	$V_{GS} = 10 \text{ V}$, $I_D = 25 \text{ A}$		75	9	mΩ
*R _{DS(ON)}	$V_{GS} = 5 \text{ V}$, $I_D = 20 \text{ A}$		12	15	
BV_{DSS}	$V_{GS} = 0 \text{ V}$, $I_D = 250 \mu\text{A}$	30			V
I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_i = 125^{\circ}\text{C}$			1 25	uA
I _{D(ON)}	V _{DS} = 10 V, V _{DS} = 10 V	50			А
I _{GSS}	V _{DS} = ±20			±100	nA
G _{FS}	V _{DS} = 5 V, V _{DS} = 20 V		20		S

Dynamic Characteristics					
Symbol	Test Conditions	Min	Тур.	Max.	Units
C _{ISS}			2020		pF
Coss	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$ $F = 1.0 \text{MHz}$		275		pF
C _{RSS}	F = 1.0MHZ		160		pF

^{*1.} Pulse width limited by maximum junction temperature



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Dynamic Characteristics					
Symbol	Test Conditions	Min	Тур.	Max.	Units
$t_{d(on)}$			10		ns
t _r	$V_{DS} = 150 \text{ V}, I_{D} = 25 \text{ A},$ $R_{G} = 2.7 \Omega, V_{GS} = 10 \text{ V}$ $R_{D} = 0.6 \Omega$		8		ns
t _{d(off)}			30		ns
tf			5		ns
$Q_g(V_{GS} = 10 \text{ V})$			23		nC
$Q_g(V_{GS} = 5 \text{ V})$	$V_{DS} = 15 \text{ V}$, $I_D = 25 \text{ A}$,		13		nC
Q_{gs}	V _{GS} = 10 V		4.7		nC
Q_{gd}			7.4		nC
Rg	$V_{GS} = 15 \text{ mV}, V_{DS} = 0, f = 1 \text{MHz}$		1.7		Ω

Source-Drain Diode Characteristics					
Symbol	Test Conditions	Min	Тур.	Max.	Units
Is				50	A
I _{SM}				140	
V _{SD}	IF = IS , V _{GS} = 0 V			1.3	V
t _{rr}			22		ns
IRM(REC)	IF = IS , V _{GS} = 0 V , dIF/dt=100A/μs		180		А
Q _{rr}			12		nC

^{*}Pulse Test : Pulse Width ≤300µs, Duty Cycle≤2%



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